

Control of the diameter and chiral angle distributions during production of single-wall carbon nanotubes

Pavel Nikolaev, ERC Inc. / NASA Johnson Space Center, Houston, TX

Many applications of single wall carbon nanotubes (SWCNT), especially in microelectronics, will benefit from use of certain (n,m) nanotube types (metallic, small gap semiconductor, etc.) Especially fascinating is the possibility of quantum conductors that require metallic armchair nanotubes. However, as produced SWCNT samples are polydisperse, with many (n,m) types present and typical ~1:2 metal / semiconductor ratio.

Nanotube nucleation models predict that armchair nuclei are energetically preferential due to formation of partial triple bonds along the armchair edge. However, nuclei can not reach any meaningful thermal equilibrium in a rapidly expanding and cooling plume of carbon clusters, leading to polydispersity. In the present work, SWCNTs were produced by a pulsed laser vaporization (PLV) technique. The carbon vapor plume cooling rate was either increased by change in the oven temperature (expansion into colder gas), or decreased via “warm-up” with a laser pulse at the moment of nucleation. The effect of oven temperature and “warm-up” on nanotube type population was studied via photoluminescence, UV-Vis-NIR absorption and Raman spectroscopy.

It was found that reduced temperatures leads to smaller average diameters, progressively narrower diameter distributions, and some preference toward armchair structures. “Warm-up” shifts nanotube population towards arm-chair structures as well, but the effect is small. Possible improvement of the “warm-up” approach to produce armchair SWCNTs will be discussed. These results demonstrate that PLV production technique can provide at least partial control over the nanotube (n,m) population. In addition, these results have implications for the understanding the nanotube nucleation mechanism in the laser oven.

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Production of armchair metallic nanotubes

Why are armchair nanotubes interesting?

Is it possible to make them?

Two approaches to affect the cooling rate of SWCNT nuclei

What about sample analysis?

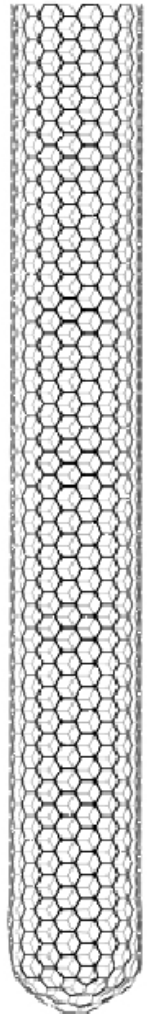
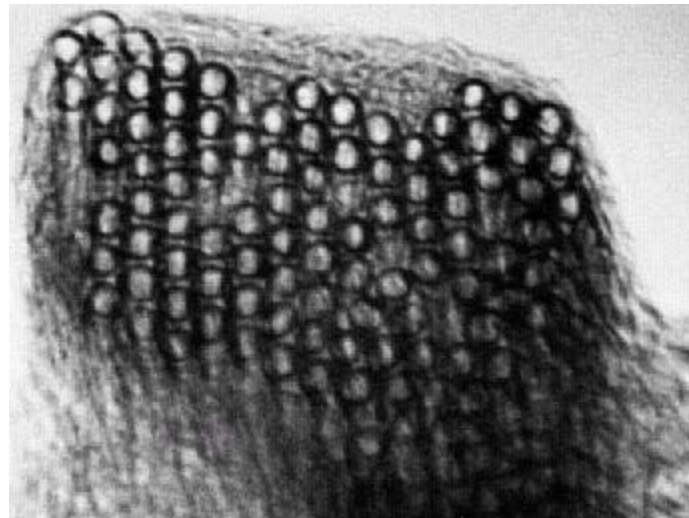
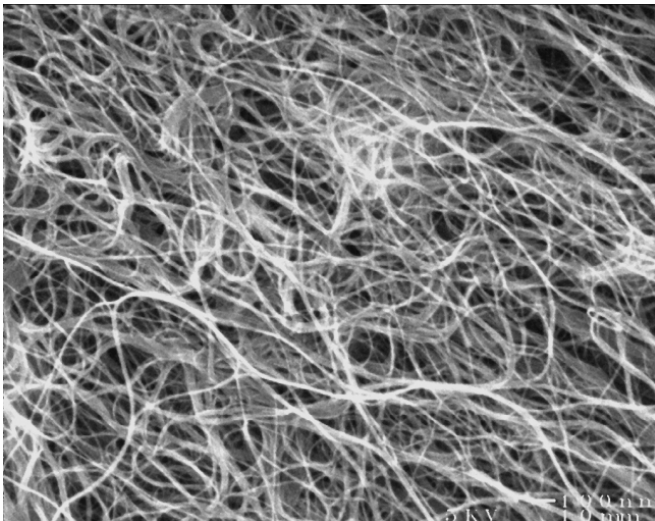
Walking my dogs, Saturday September 13th. Hello, Ike!



What are single-wall carbon nanotubes?

MOLECULAR PERFECTION & EXTREME PROPERTIES

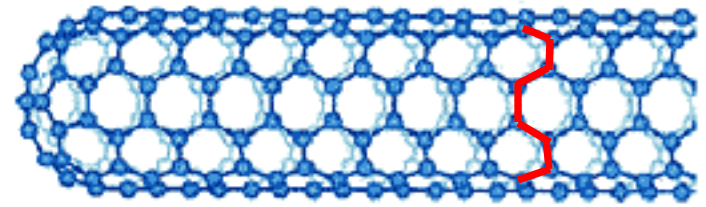
- The strongest fiber possible
- Thermal conductivity of diamond, anisotropic
- The unique chemistry of sp^2 carbon
- The scale and perfection of DNA
- Selectable electrical properties: Metallics and Semiconductors
- *The ultimate engineering material*
- *SWCNT behaves as a molecule and as a macro object at the same time!*



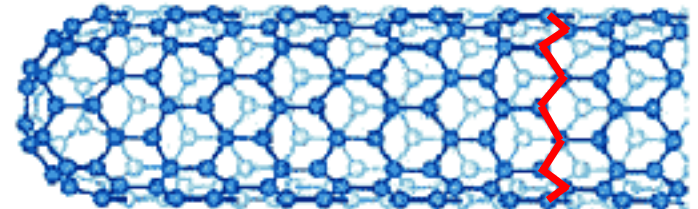
Let's roll

- The graphene sheet can be rolled in many possible ways
- Armchair, $\alpha = 30^\circ$
- Zig-zag, $\alpha = 0^\circ$
- Intermediate, $0^\circ < \alpha < 30^\circ$

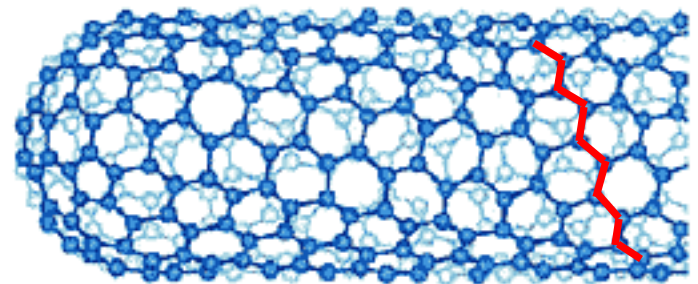
Electrical properties depend on this.



Armchair ($\alpha = 30^\circ$)



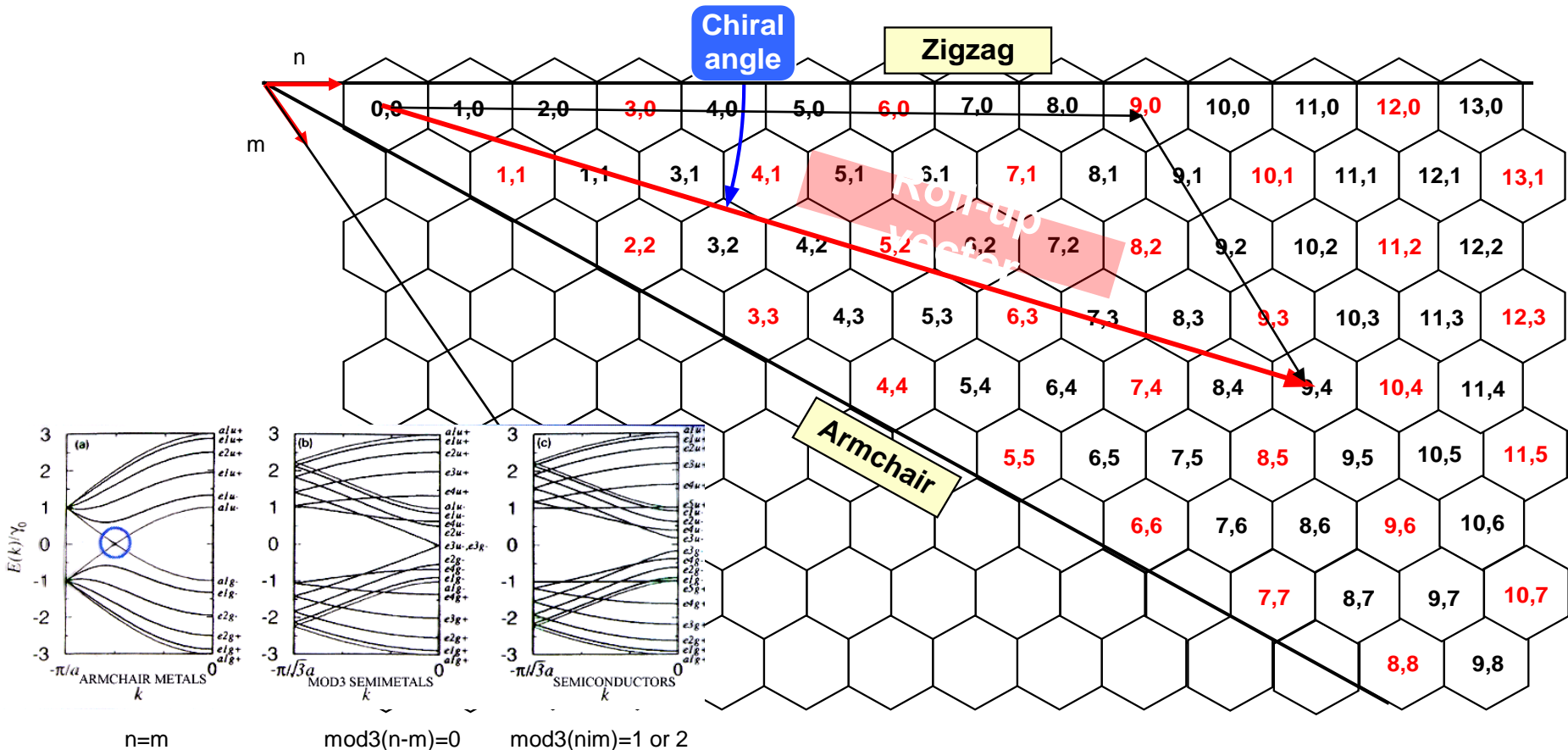
Zigzag ($\alpha = 0^\circ$)



Intermediate ($0^\circ < \alpha < 30^\circ$)

Rolling Graphite: n,m Vectors

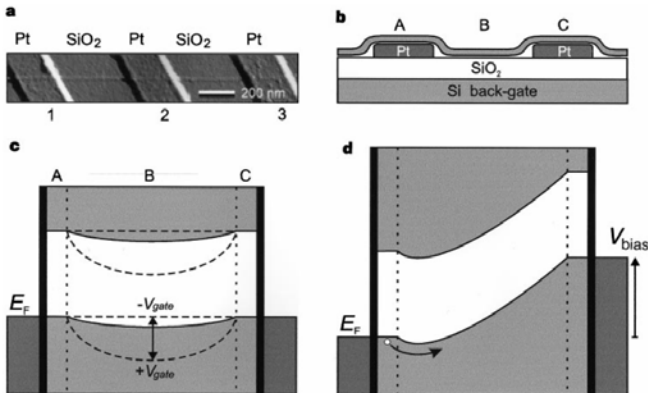
- Of the 864 distinct types between 0.7 and 2.8 nm diameter,
- ~ 1/3rd are semi-metals
- ~ 2/3rd direct band-gap semiconductors
- Only 16 are armchair metals!
- Even smaller fraction for typical PLV-produced SWNT in 0.9 – 1.6 nm diameter range



Nanotubes in microelectronic devices

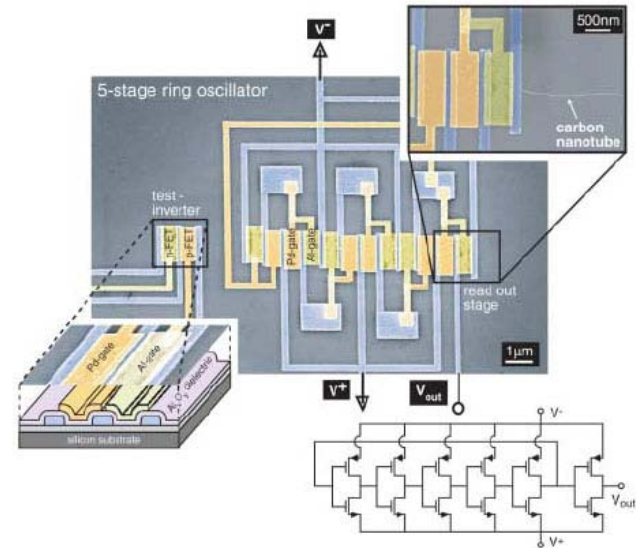


1997 - 1998



Room-temperature transistor based on a single carbon nanotube

Sander J. Tans, Alwin R. M. Verschueren & Cees Dekker,
Nature vol. 393, 7 May 1998



2005-2006

An Integrated Logic Circuit Assembled on a Single Carbon Nanotube

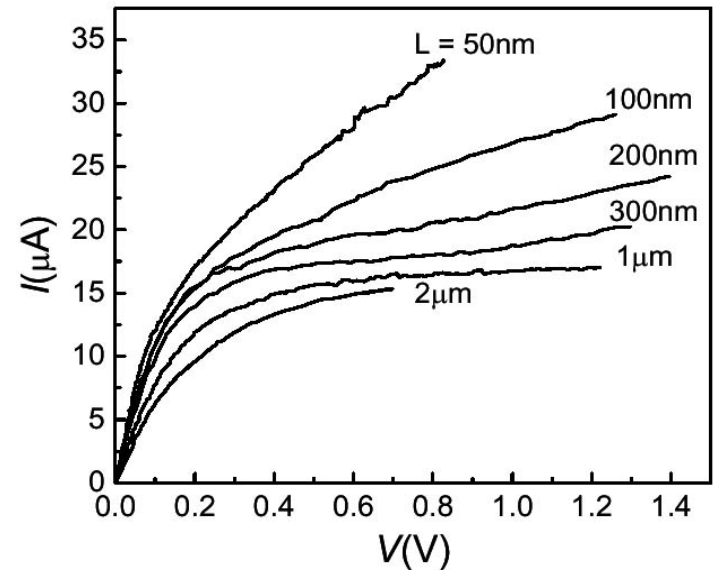
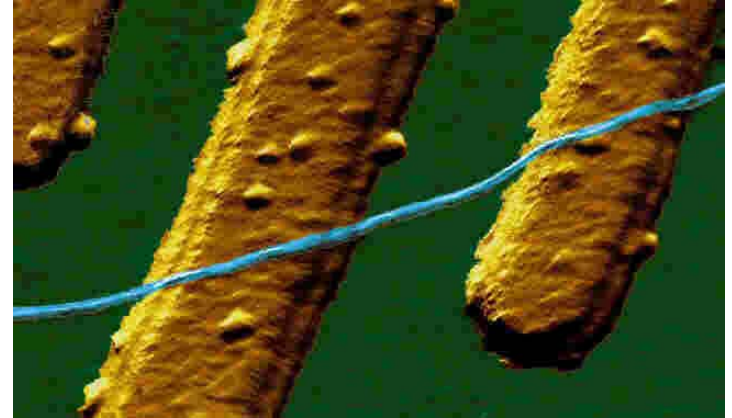
Zhihong Chen, Joerg Appenzeller, Yu-Ming Lin,
Jennifer Sippel-Oakley, Andrew G. Rinzler,
Jinyao Tang, Shalom J. Wind, Paul M. Solomon,
Phaedon Avouris,
Science vol. 311, 24 March 2006

More recent and realistic proposals: Can we use metallic SWNT as interconnects on microchips?

Metallic nanotubes

What are they good for?

- Interconnects on microchips – certainly an excellent idea.
- Measurements on individual metallic SWNT on Si wafers with patterned metal contacts
- Single tubes can pass 20 μA for hours
- Equivalent to roughly a billion amps per square centimeter!
- Conductivity measured twice that of copper
- Ballistic conduction at low fields with mean free path of 1.4 microns
- Similar results reported by many
- Common metals give away their electrons too easily at these conditions and oxidize away. sp^2 electrons are much more stable!



Armchair metallic nanotubes

But nanotubes have finite length

Can we make a good electrical conductor out of discontinued wires?

Answer – resonant quantum tunneling

An interesting feature of this junction is the sensitive dependence of conductance on the contact length, l . Figure 2 shows the conductance values for armchair-armchair and

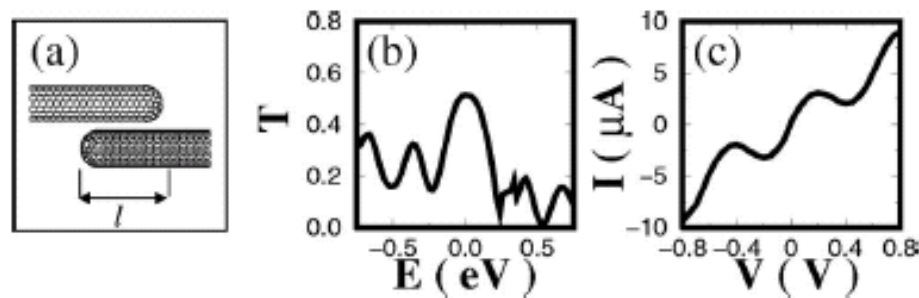
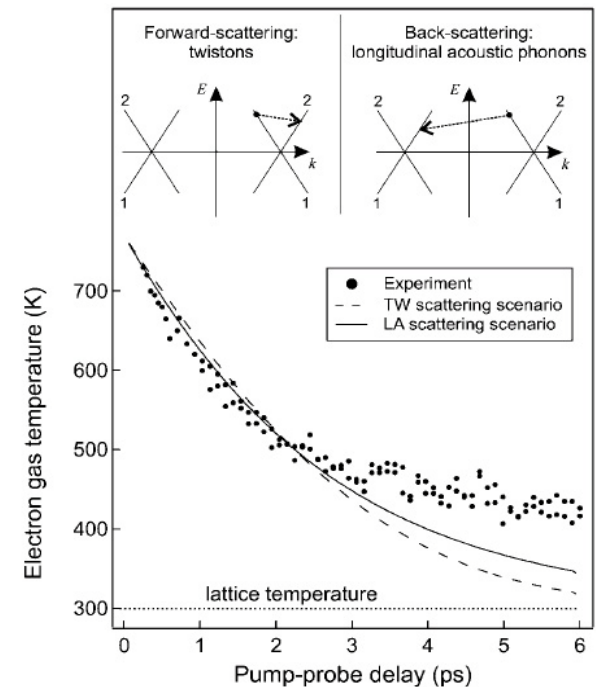
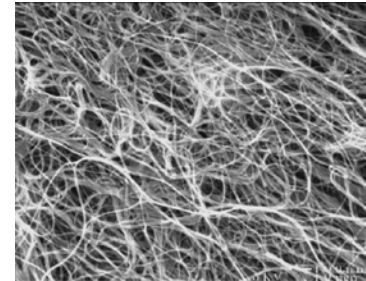
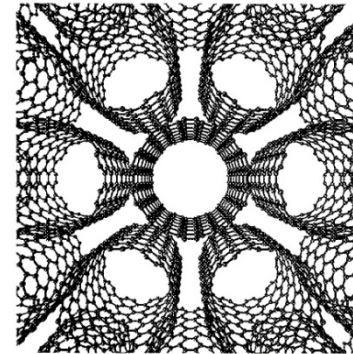


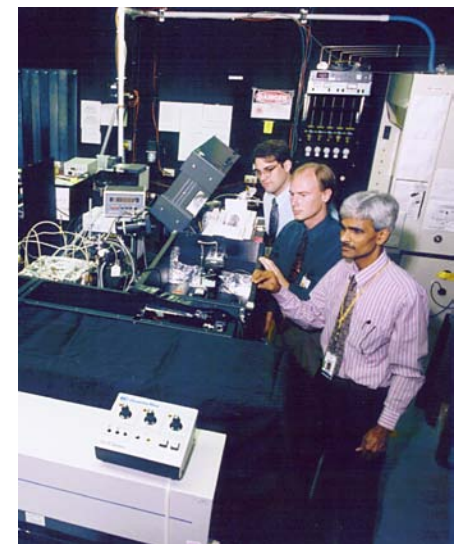
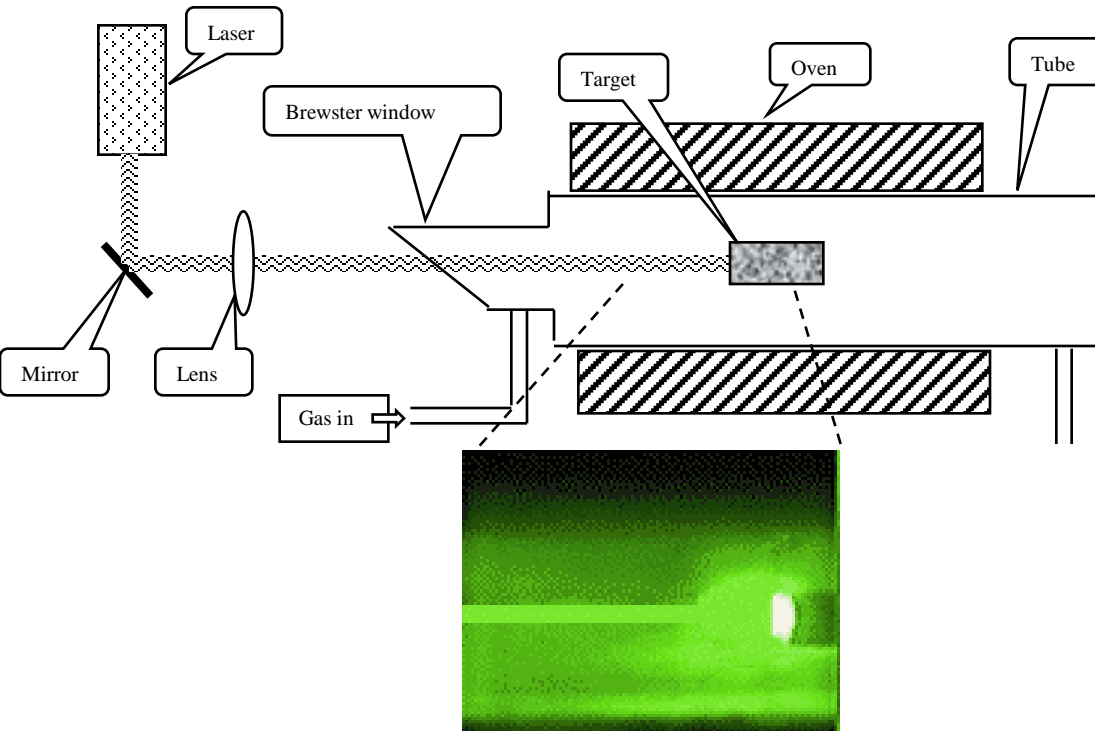
FIG. 1. (a) A two-terminal nanotube junction can be formed by bringing two tubes' ends together in parallel and pointing opposite directions (l is the contact length). (b) The transmission coefficient T of the two armchair tube [(10,10)-(10,10)] junction as a function of energy E for $l=64$ Å. Interference of electron waves yields resonances in transport. (c) Current-voltage characteristics of the (10,10)-(10,10) junction for $l=46$ Å.

Armchair metallic nanotubes

- Experimental evidence of resonant tunneling
- Indirect indication of conductivity by measuring lifetimes of photo-excited electrons
- Cooling mechanism is interaction with phonons – just like electrical resistivity
- Anomalously long life-times yield mean free path of 15 microns (10x single tubes)
- Based on bundles in ‘buckypapers’ – good local symmetry and clean, but still based on mixture of metals and semi-conductors
- Results imply 10 – 25x better conductivity than copper

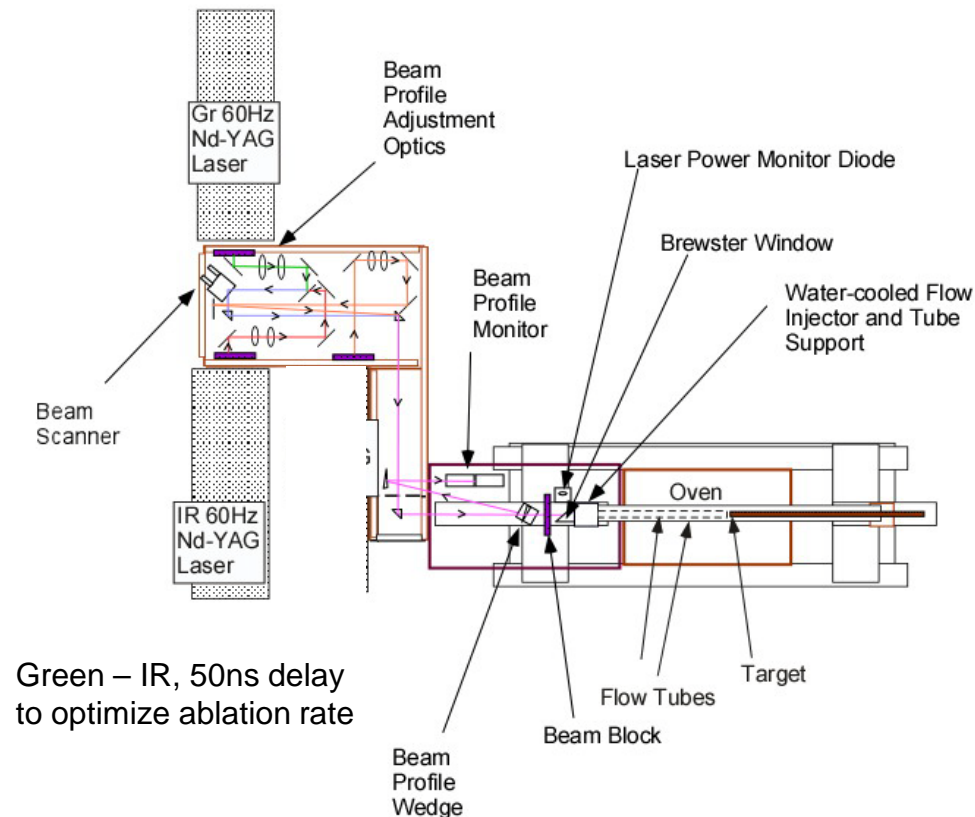


SWCNT production by PLV at Johnson Space Center

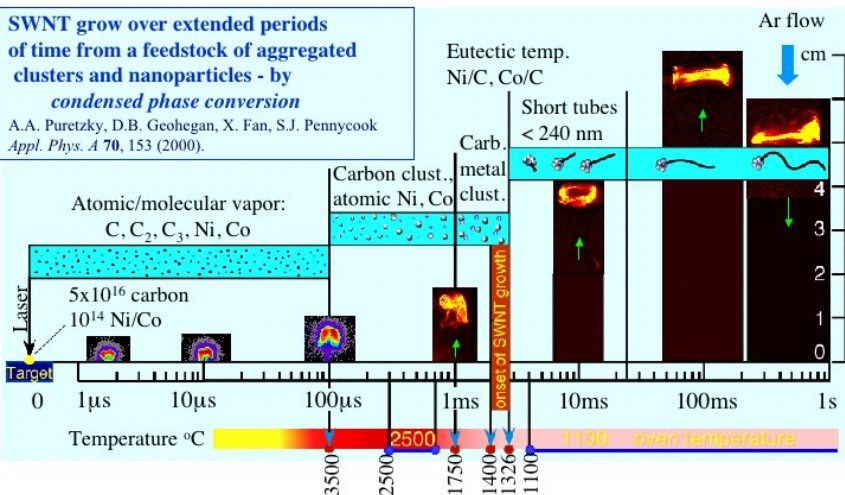


So far all optimization was centered on increasing production rate and nanotube yield

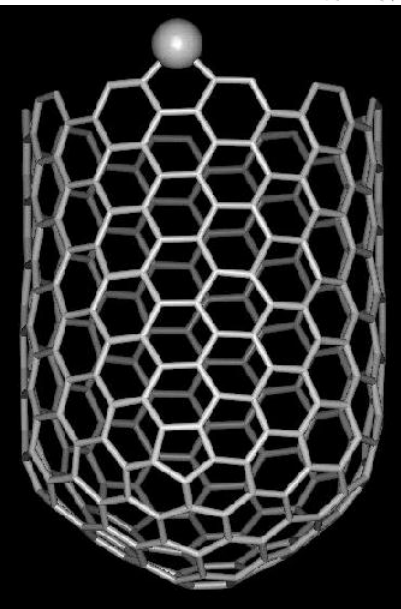
Can we optimize for the nanotube type?



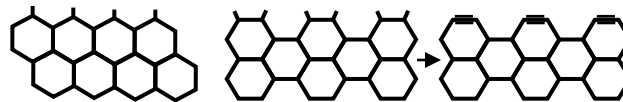
Nanotube nucleation in laser oven



- Nanotube nucleation occurs in the 100 μs – 1 ms time frame, from carbon clusters and catalyst vapor.
- Carbon has much lower vapor pressure than metal catalyst
- Carbon atoms condense first and form small graphene sheets that start closing into cages
- Without metal, cage closes into a fullerene (~40% yield, and 1-3% in typical nanotube sample)
- When metal atom lands on the edge, it satisfies dangling bonds and prevents cage from closing
- When cluster exceeds 500-600 carbon atoms, it's shape is fixed kinetically, and the nanotube keeps on growing by adding incoming carbon clusters to the open end

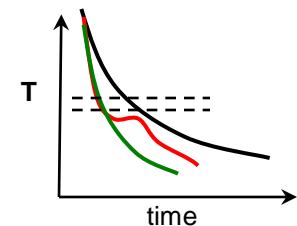


- Formation of the nanotube nuclei with fixed (n,m) happens on the time scale of 100 μs – 1 ms – very fast. Subsequent growth occurs on the few seconds scale
- Interesting observation: armchair (n=m) nuclei are ~15% more stable energetically due to formation of triple bonds. However, equilibrium is not reached due to the very fast nature of the nucleation



$$\epsilon_e \text{ zig-zag} > \epsilon_e \text{ armchair}$$

- Can we affect nanotube nucleation?
- **Faster nucleation – expansion into a colder gas**
- **“Warm-up”: hit nanotube nuclei with more energy after the nucleation time, slow down cooling, and let them to nucleate longer.**



Nanotube production at lowered temperature.

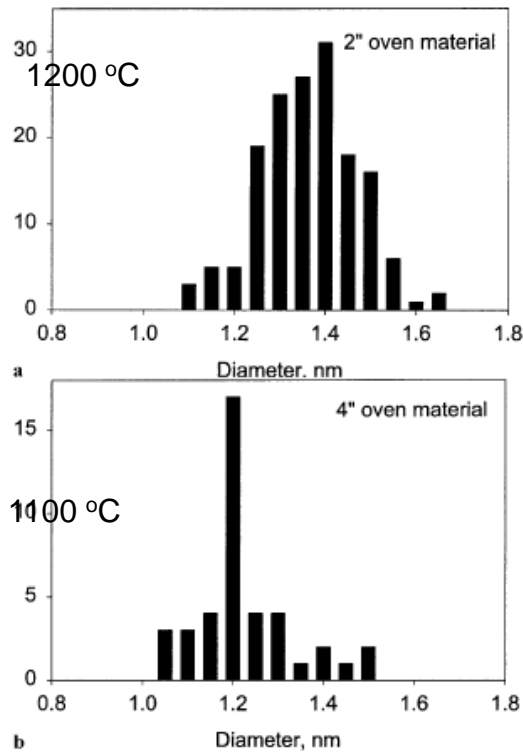


Fig. 5. a The diameter distribution of SWNT made in the 2" system (1200 °C). b The diameter distribution of SWNT made in the 4" system (1100 °C).

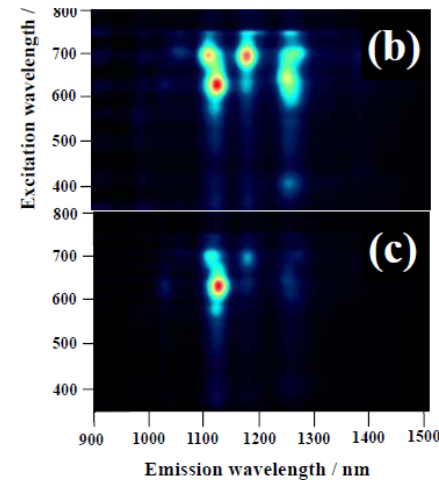
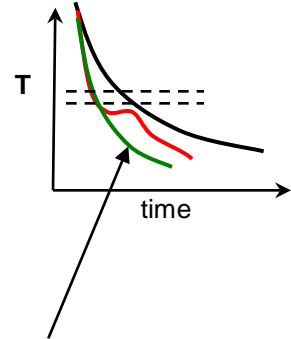


Fig. 4. (Color online) Photoluminescence mapping of dispersed SWNTs in sodium dodecyl benzenesulfate (SDBS) solution. (a) HiPco nanotubes. (b) SWNTs prepared in nitrogen atmosphere. (c) SWNTs prepared in Ar atmosphere.



Co/Ni catalyst, 1200 and 1100 °C

Rh/Pd catalyst, 1150 °C
(vs. normal 1400 °C)

1.A. G. Rinzler, J. Liu, H. Dai, P. Nikolaev, C. B. Huffman, F. J. Rodriguez-Macias, P. J. Boul, A. H. Lu, D. Heymann, D. T. Colbert, R. S. Lee, J. E. Fischer, A. M. Rao, P. C. Eklund, and R. E. Smalley, *App. Phys. A* 67, 29 (1998). S. Suzuki, N. Asai, H. Kataura, and Y. Achiba, *Eur. Phys. J. D* 43, 143 (2007).

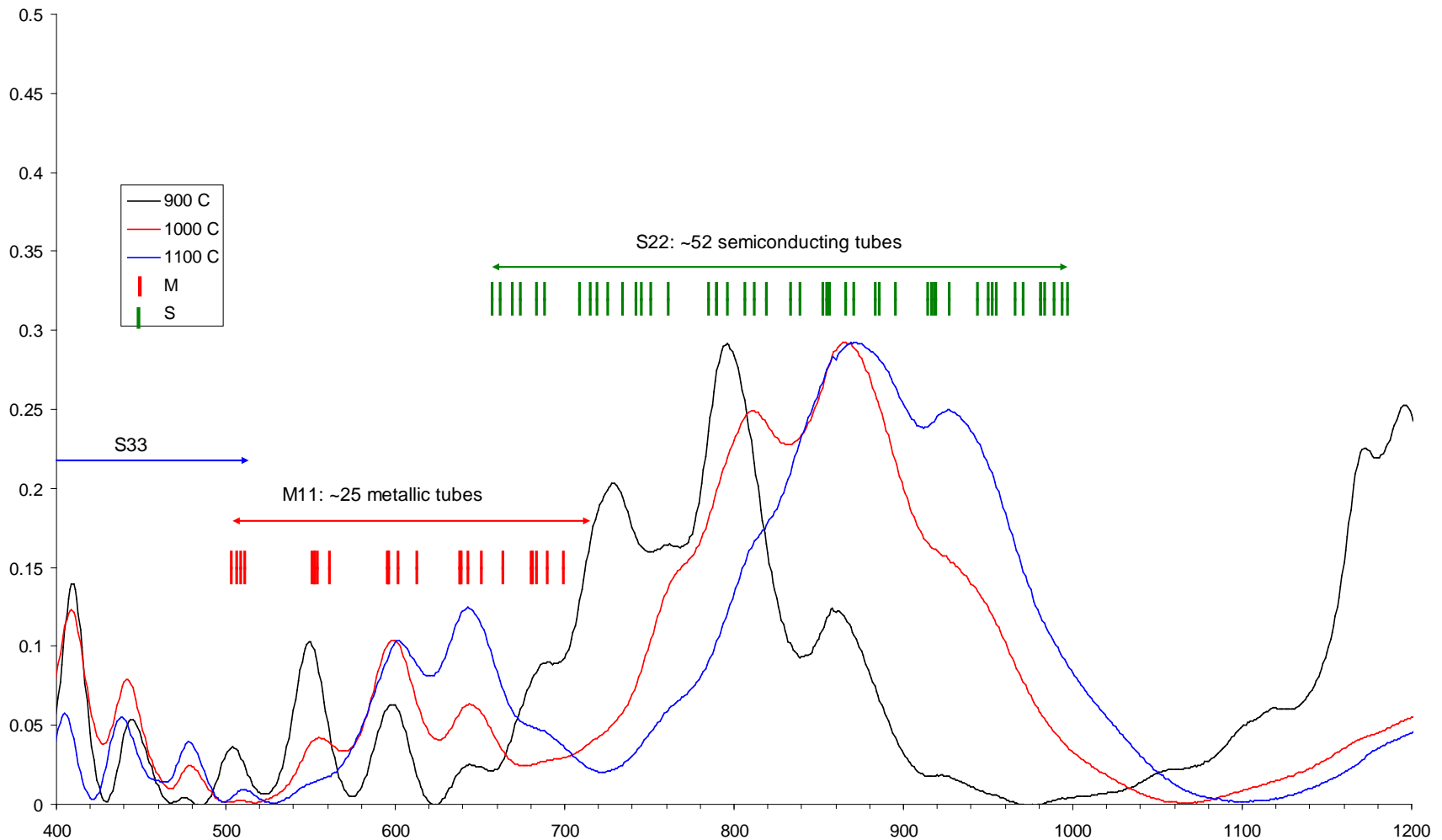
So, we decided to try 1100, 1000 and 900 °C temperatures.

Everything else – the same: Co/Ni catalyst (1 at. % each). Argon buffer gas at 500 Torr pressure and 100 sccm flow rate. Green/IR ablation laser combination (2nd and 1st harmonics of Nd:YAG lasers) with 50 ns pulse delay, 1.6 J/cm² energy density each and 60 Hz repetition rate.

Preparing these samples was easy.

What needs to be done to understand how temperature influences SWCNT population?

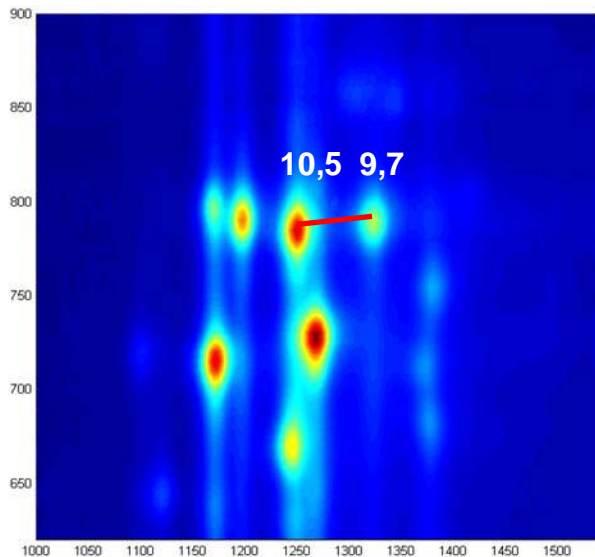
Absorption spectra: too much overlapping of the spectral features



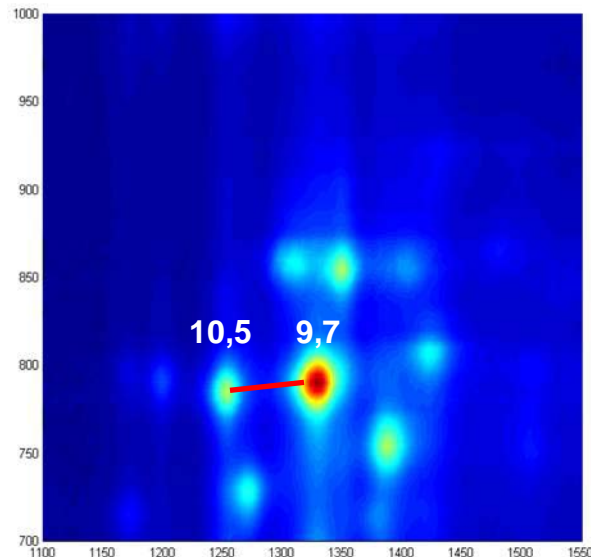
Discriminate semiconducting tubes with the help of photoluminescence .

- Full PL maps on J-Y Spex Fluorolog 3-211 equipped with an LN₂-cooled InGaAs NIR detector. 5 nm excitation step, 3 nm detection step, 5 nm slits.
- Only 12 - 14 semiconducting tubes.
- In order to measure peak amplitudes precisely, each peak is fitted with 2-d Lorentzian

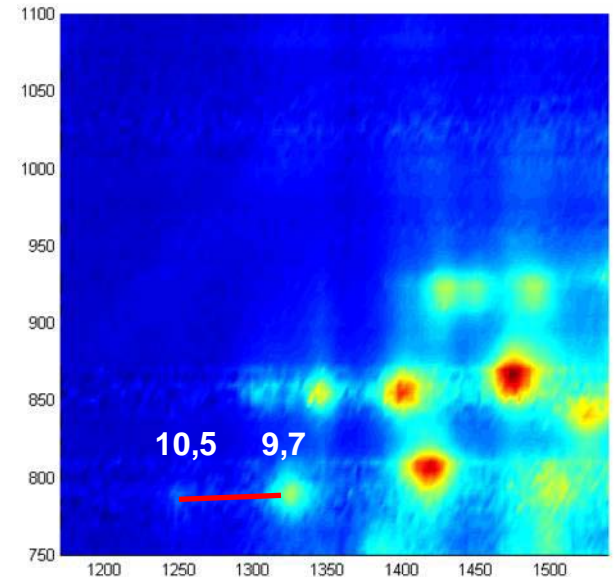
900 C



1000 C

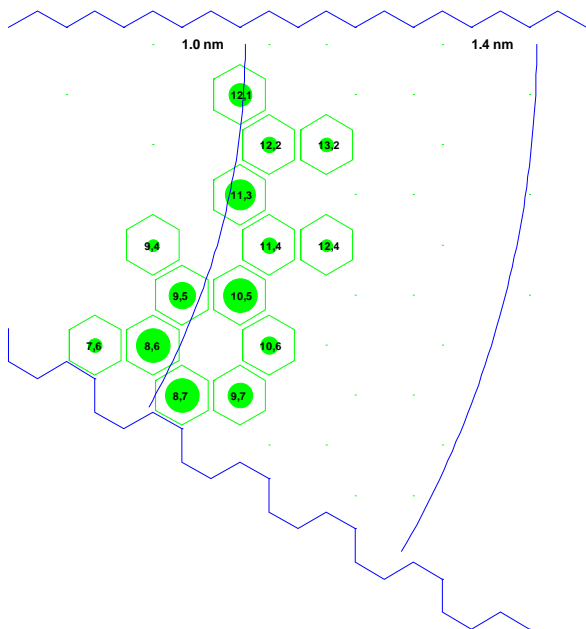


1100 C

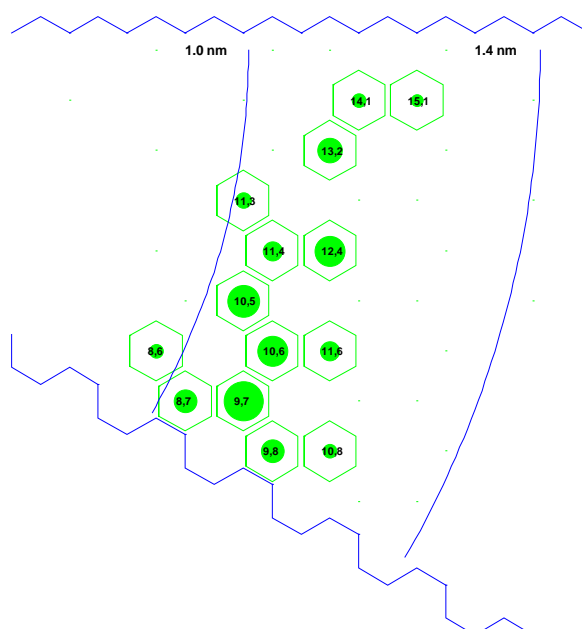


Resulting chiral maps: semiconductors only

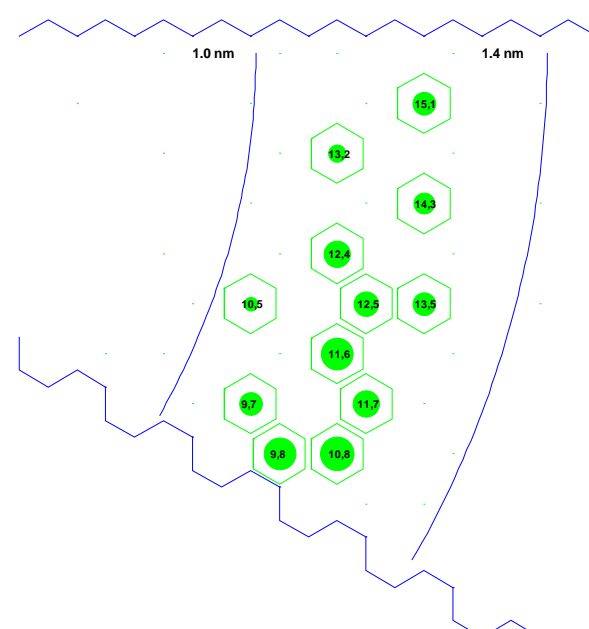
900



1000



1100



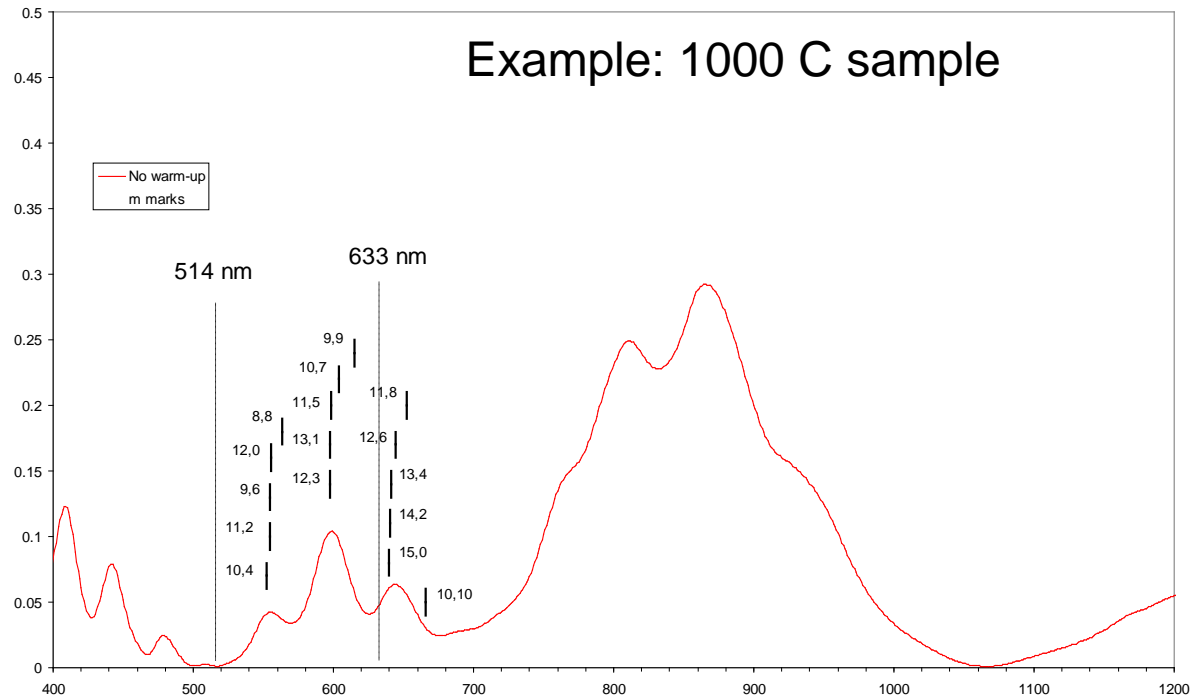
Metallic tubes: no PL makes similar analysis impossible.

On absorption spectra each metallic peak is a superposition of several possible tubes – impossible to deconvolute

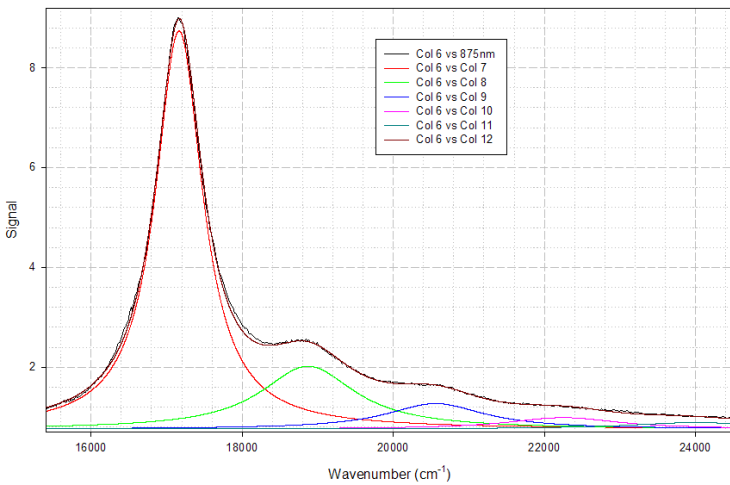
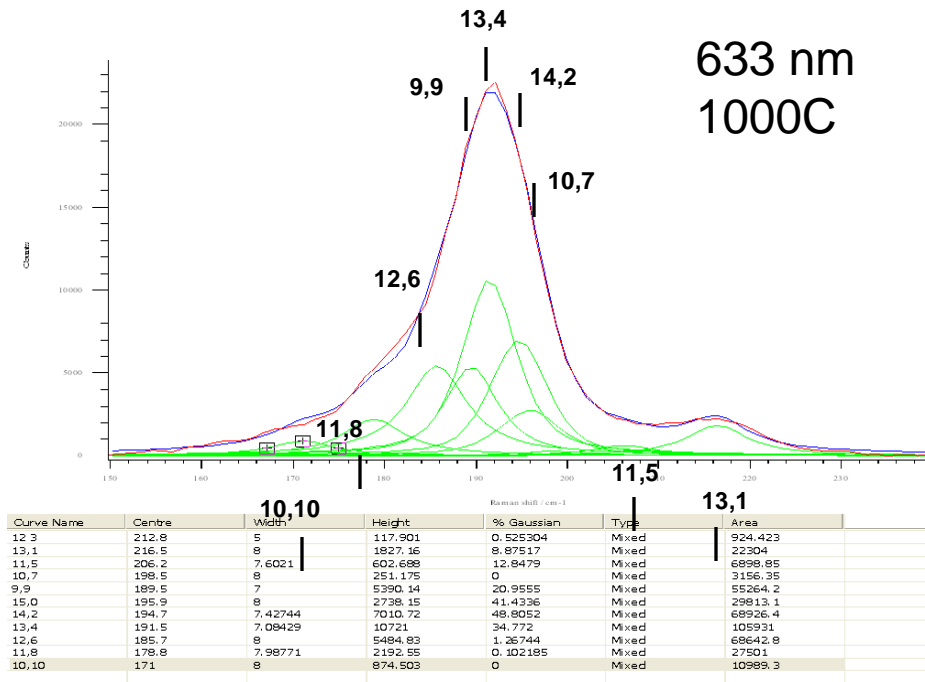
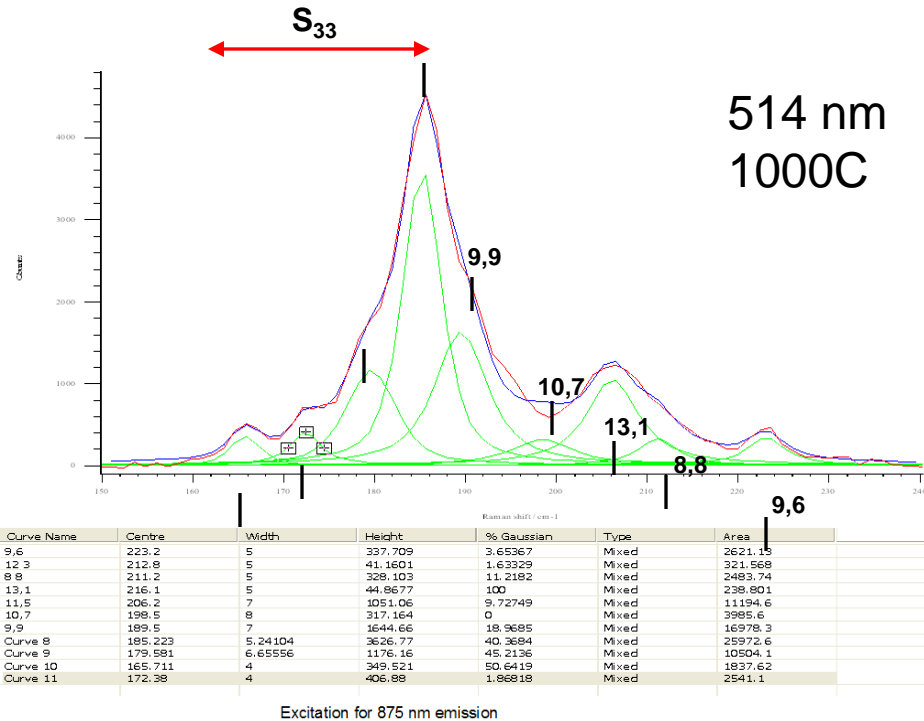
Raman: 514 nm excitation is reasonably in tune with first peak. Will also excite large diameter semiconductors on S_{33} transition

633 nm excitation is reasonably in tune with 2nd and 3rd peaks

RBM frequencies are much better known and reproducible.

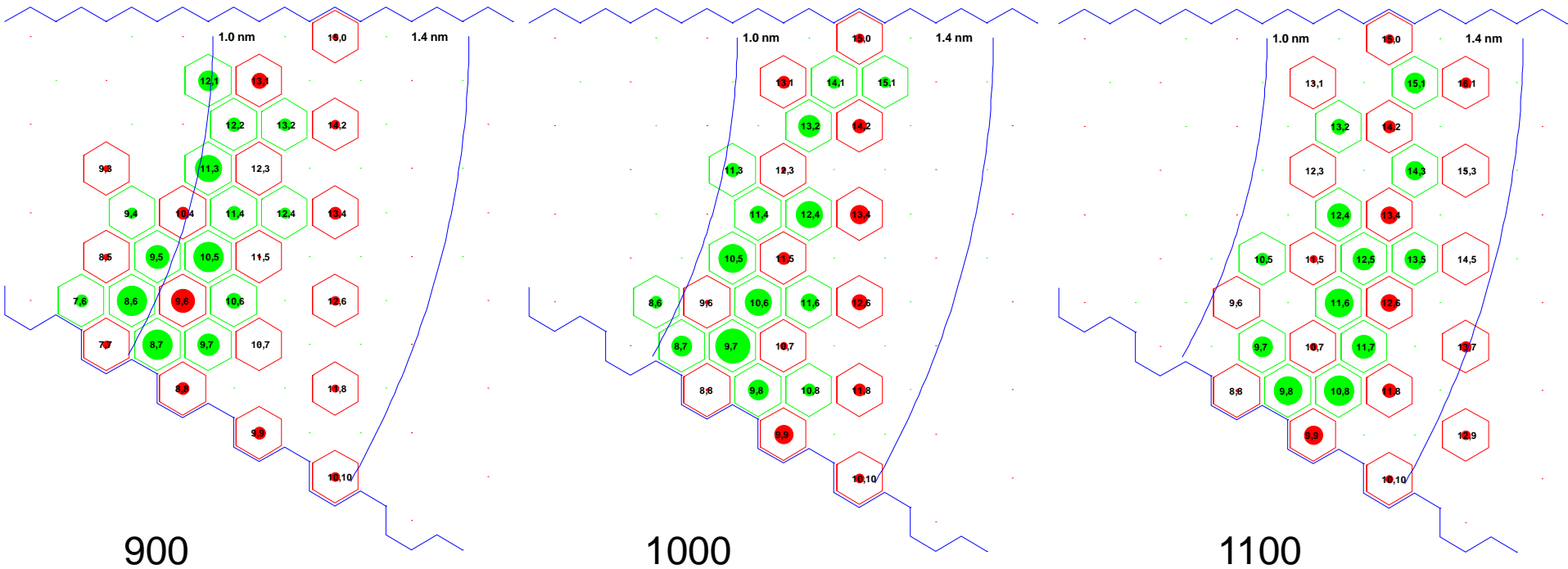


Raman spectra deconvolution



Excitation is off-resonance:
Use excitation profile and assume that linewidth and overtone tail scale with the transition energy
RBM frequencies are known to shift due to bundling, etc. However it is possible to find an “anchor” tube ((9,6), (13,1) in this case) and determine the RBM frequencies of the other tubes

Resulting chiral maps: semiconductors AND metallics.



The larger diameter tubes have chiral angles closest to arm-chair (30°)

Does this observation agree with the nucleation model?

E_c , is to a good approximation independent of tubulet radius (determined by 5 pentagons in a hemisphere).

$E_r = \varepsilon_r L / R$, where ε_r is bending **stiffness of a graphene sheet**, L is length of the cylinder, and R is tubulet radius.

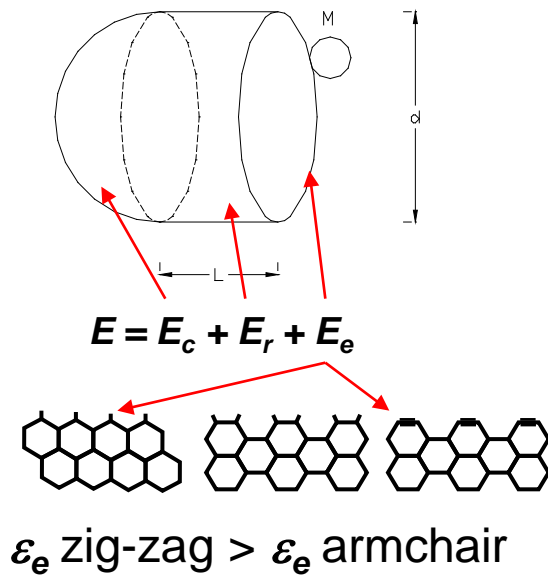
$E_e = 2\pi R \varepsilon_e$, where ε_e is energy of the open edge per unit length.

Minimization of the energy with respect to R for a fixed number of carbon atoms N yields:

$$R \sim (N \varepsilon_r / \varepsilon_e)^{1/3}.$$

Therefore, decrease in the edge energy ε_e will lead to increase in the diameter of a nanotube nucleus.

If ε_e armchair < ε_e zig-zag, nuclei with the edge closest to arm-chair structure will nucleate largest diameter nanotubes.



“Warm-up” approach: what should be the energy density and time delay?

Time delay: 500 μs . (decided rather arbitrarily)

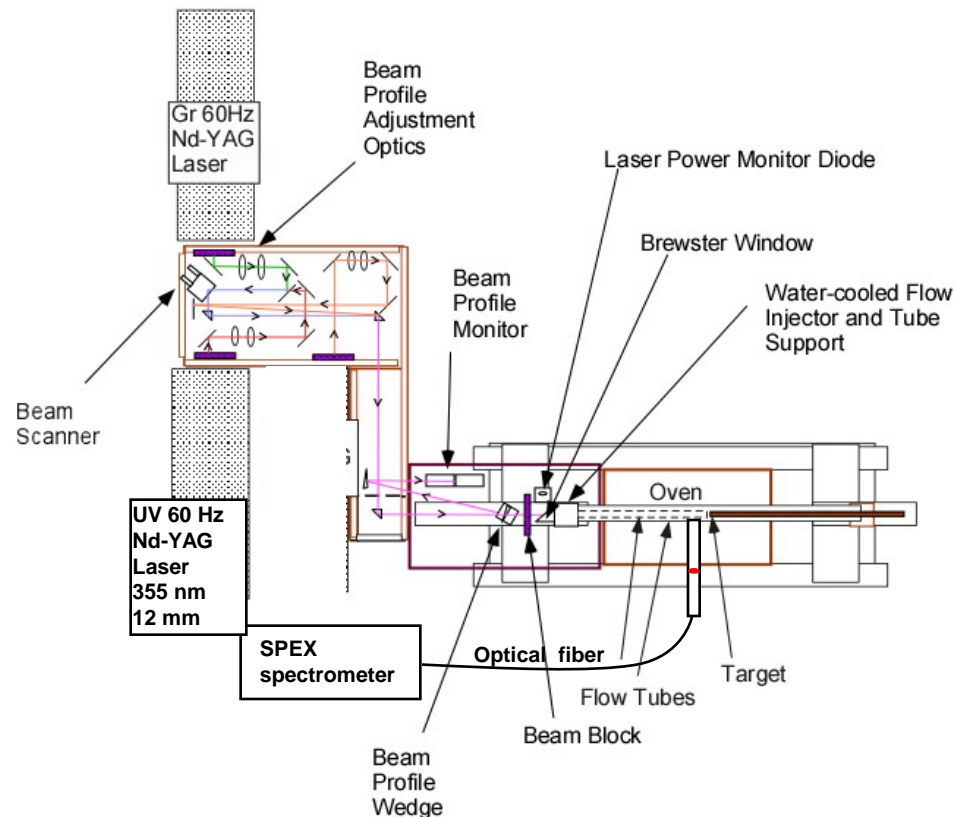
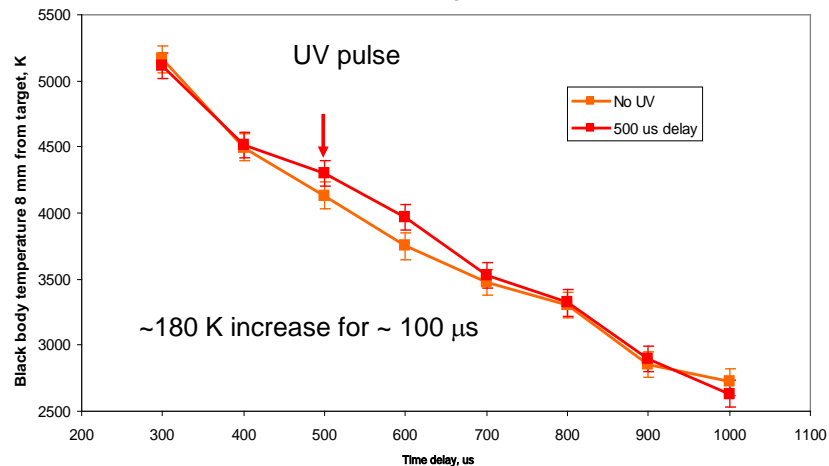
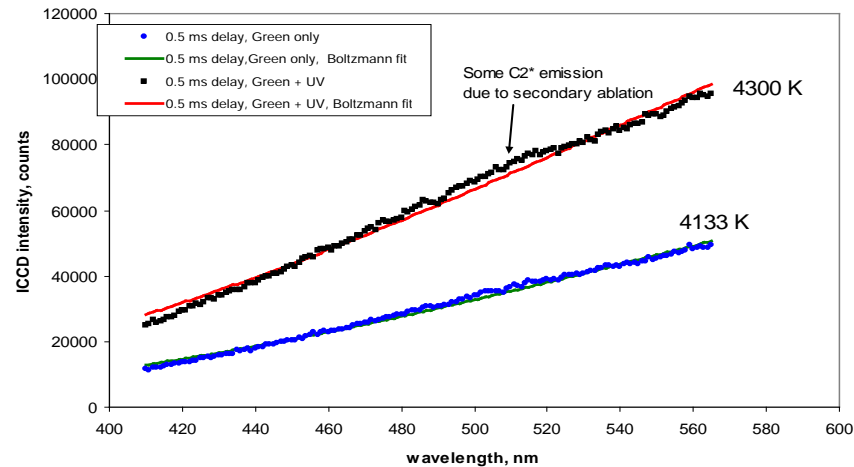
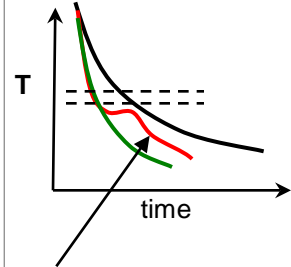
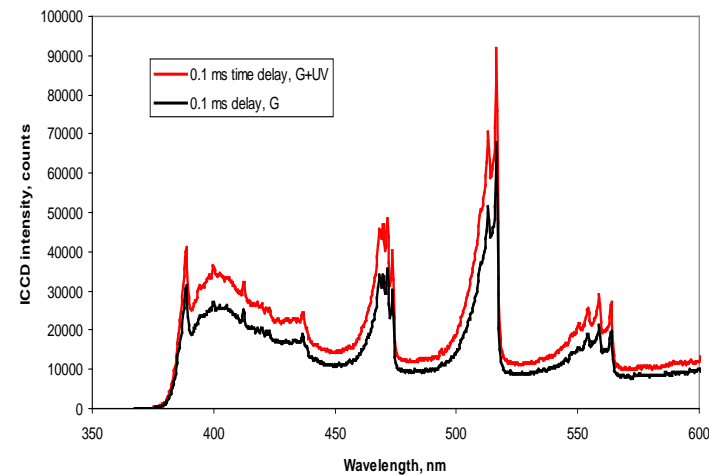
Energy density:

Green energy: 1.6 J/cm²

-UV: avoid secondary ablation

-UV energy varied, looking at increase in C₂^{*} emission on top of black body continuum. Secondary ablation threshold ~ 0.1 J/cm² for 500 μs delay.

Oven temperature: 1000 °C. We need to bring SWCNT diameter within the reach of spectroscopy tools.

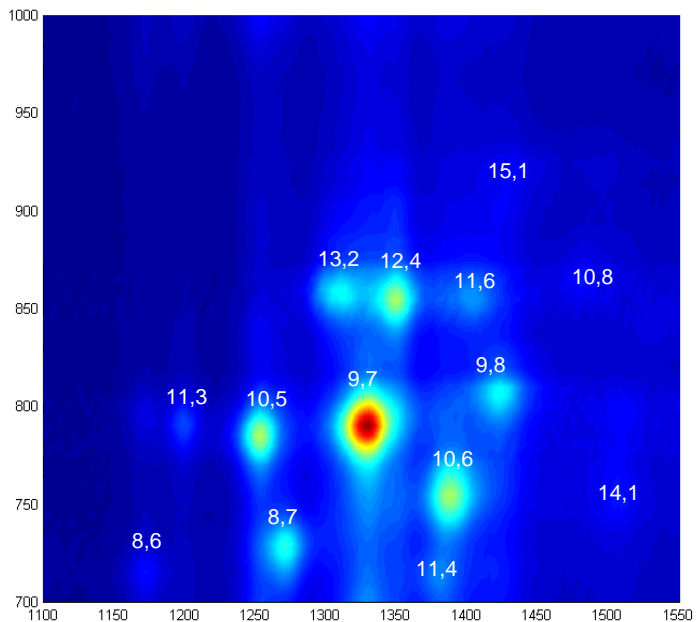


Nanotube population: is it enriched in armchair structures as a result?

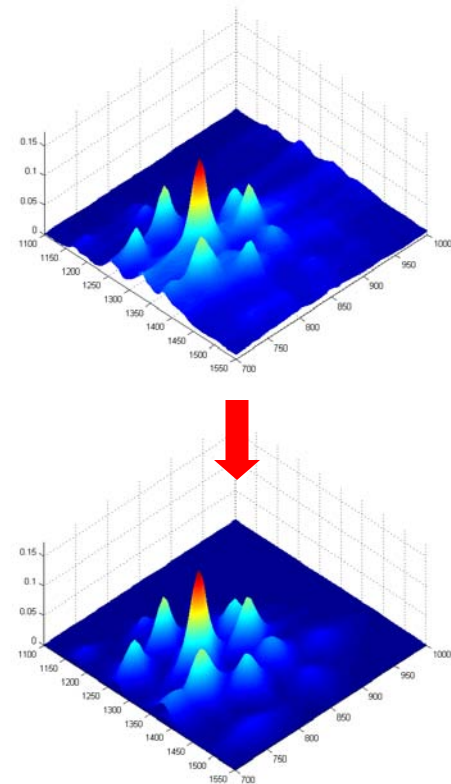
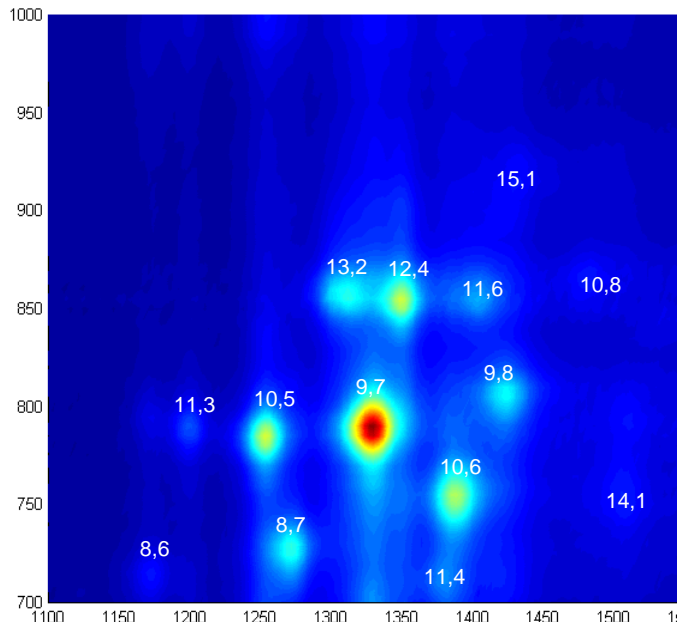
Discriminate semiconducting tubes with the help of photoluminescence .

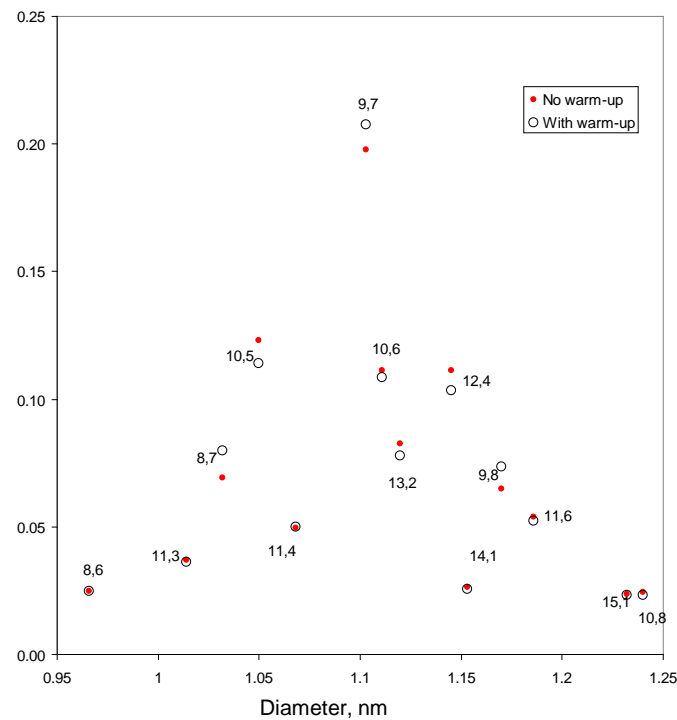
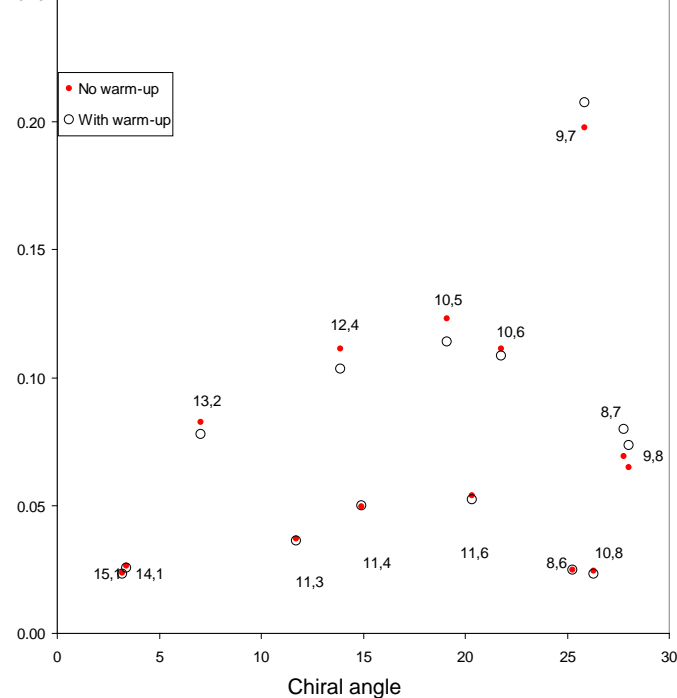
- Full PL maps on J-Y Spex Fluorolog 3-211 equipped with an LN₂-cooled InGaAs NIR detector. 5 nm excitation step, 3 nm detection step, 5 nm slits.
- Only 14 semiconducting tubes.
- Maps appear similar. In order to measure small differences, each peak is fitted with 2-d Lorentzian

No warm-up



With warm-up





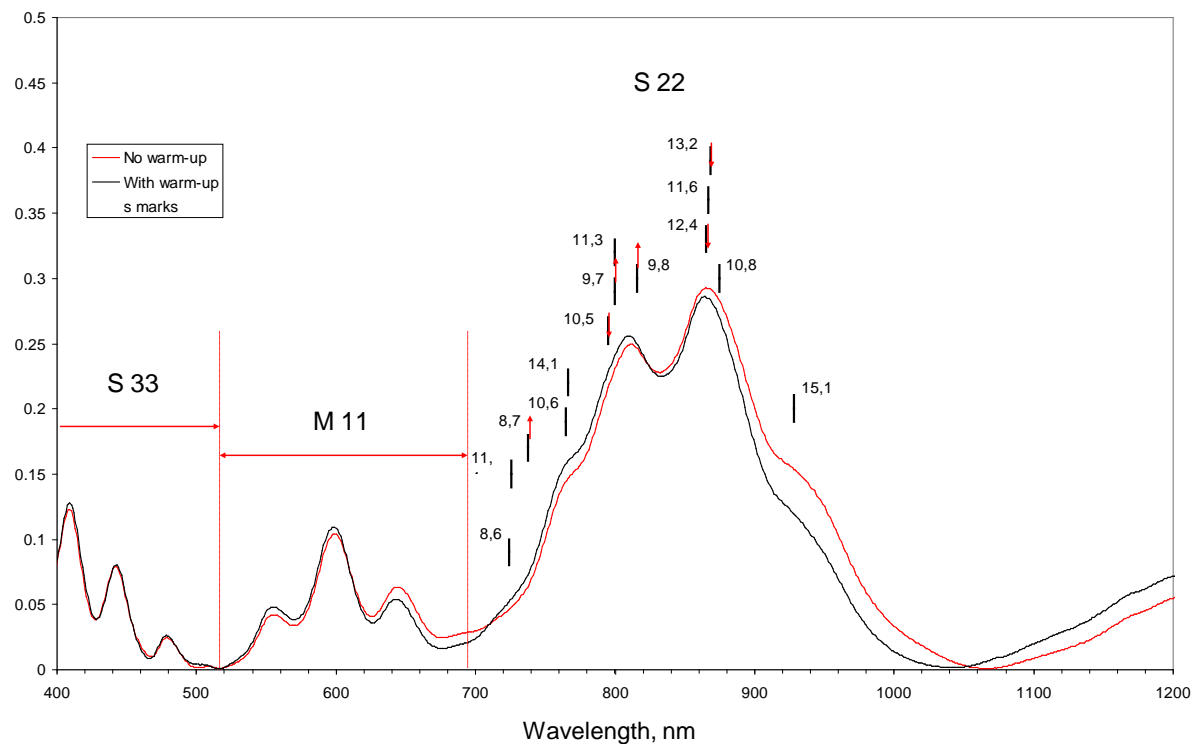
PL data:

(9,7), (9,8), and (8,7) increase with warm-up
-all have chiral angles $>25^\circ$, close to armchair

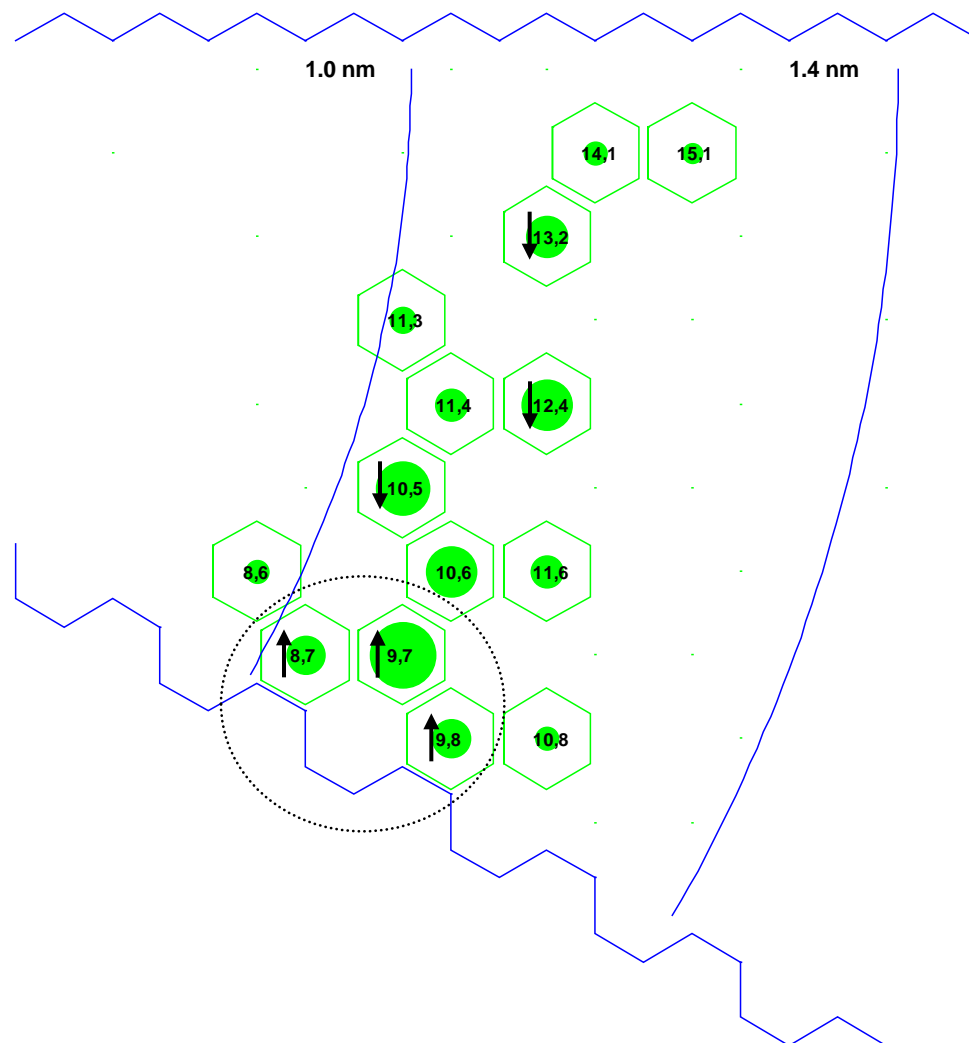
(13,2), (12,4), and (10,5) decrease with warm-up
-all have chiral angles $<20^\circ$

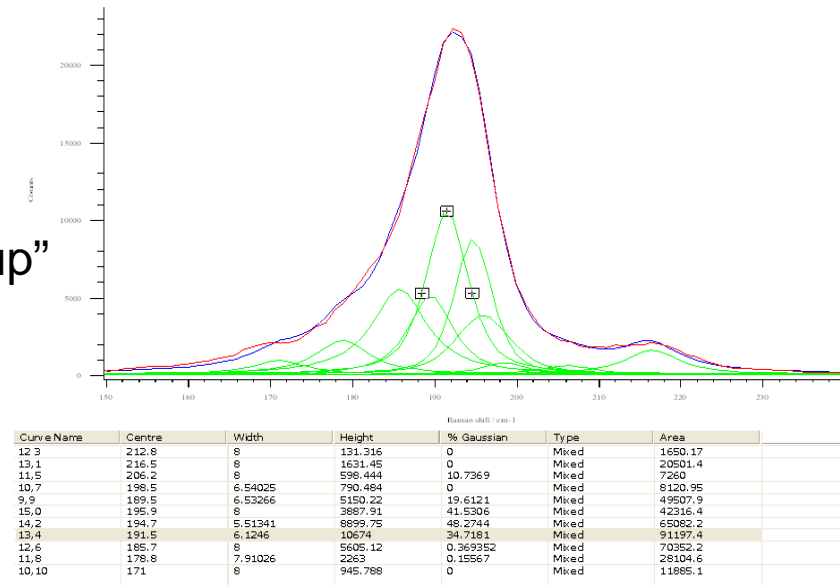
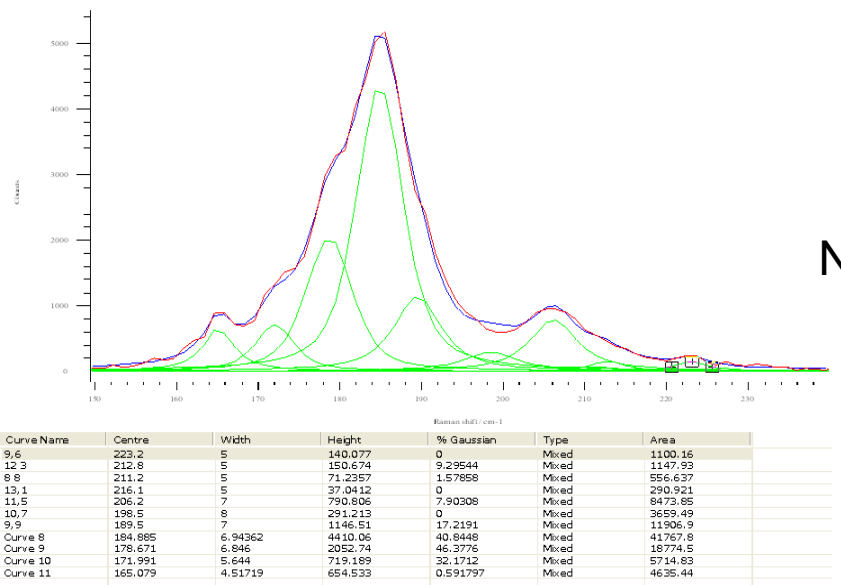
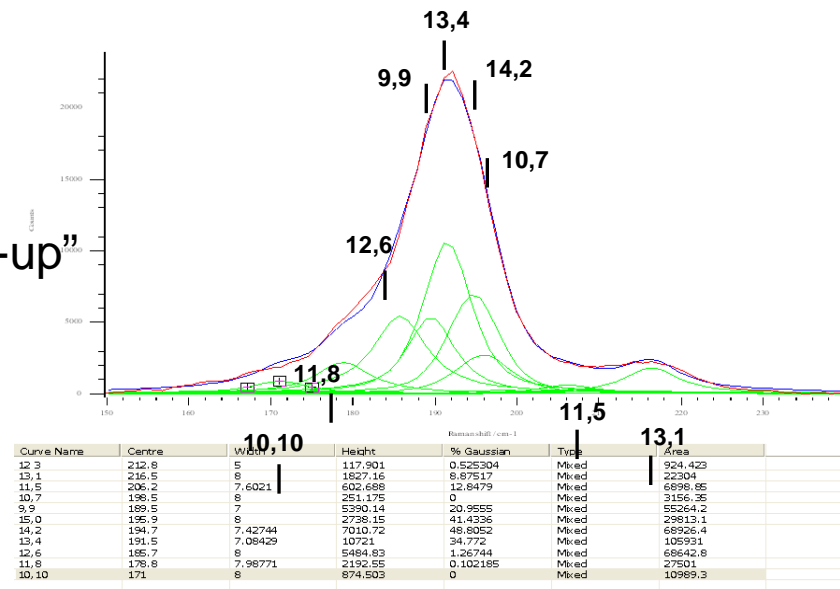
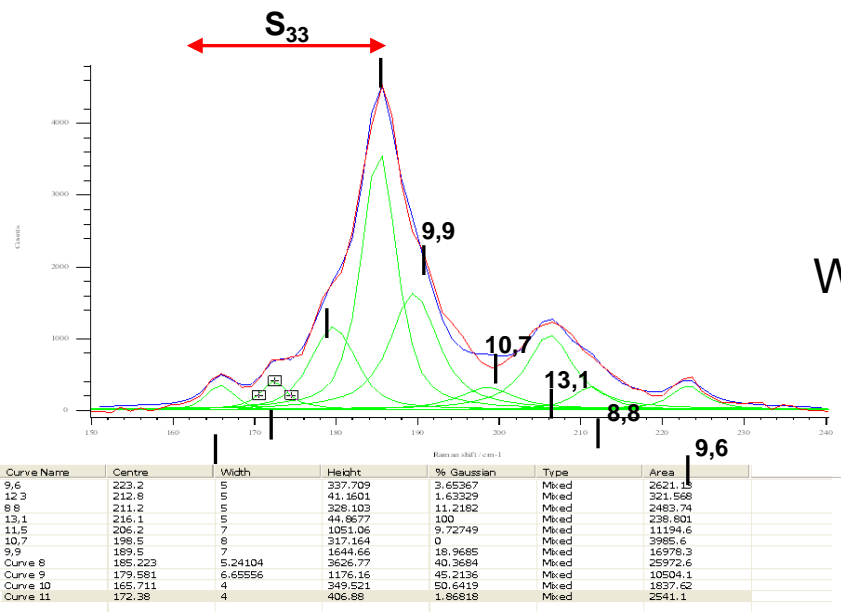
No clear diameter dependence

Absorption data is consistent with this.



Chiral map.





Raman data:

(8,8), (10,7), and (9,6) increase with warm-up
-all have chiral angles $>23^\circ$, close to armchair

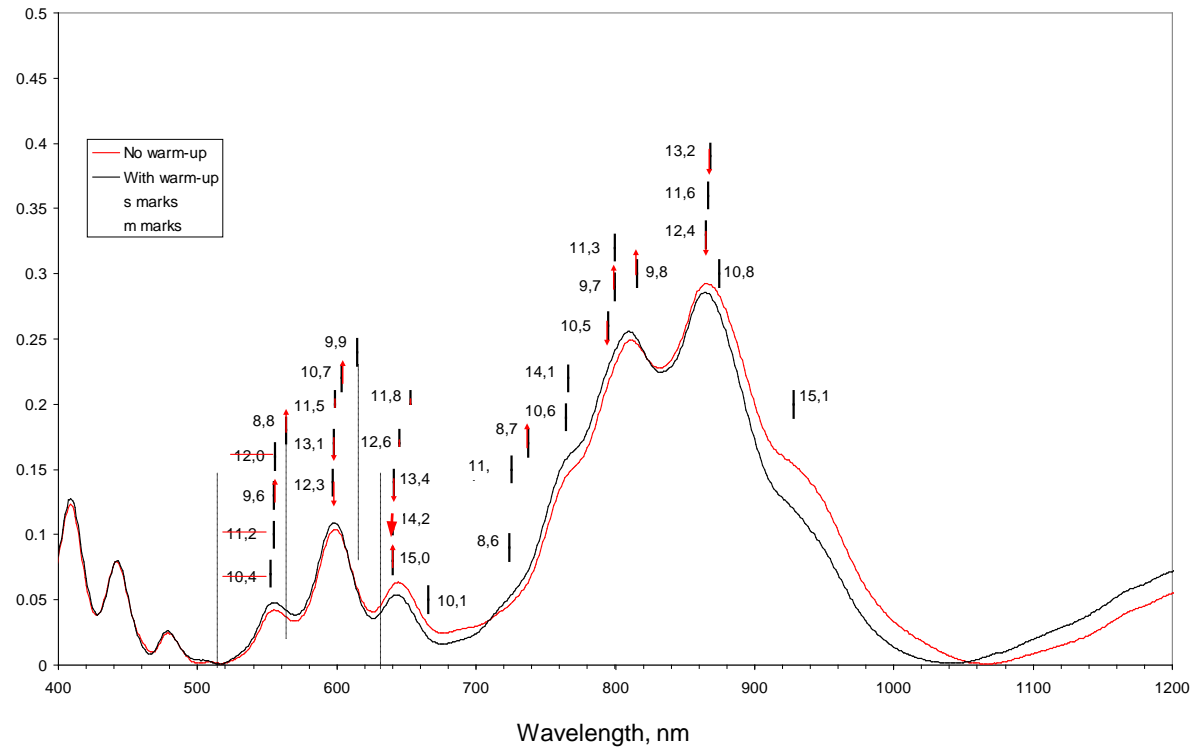
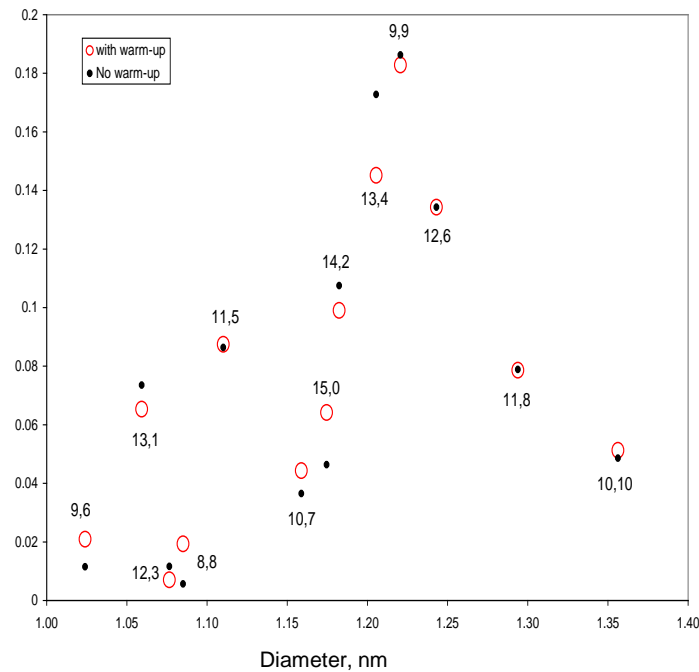
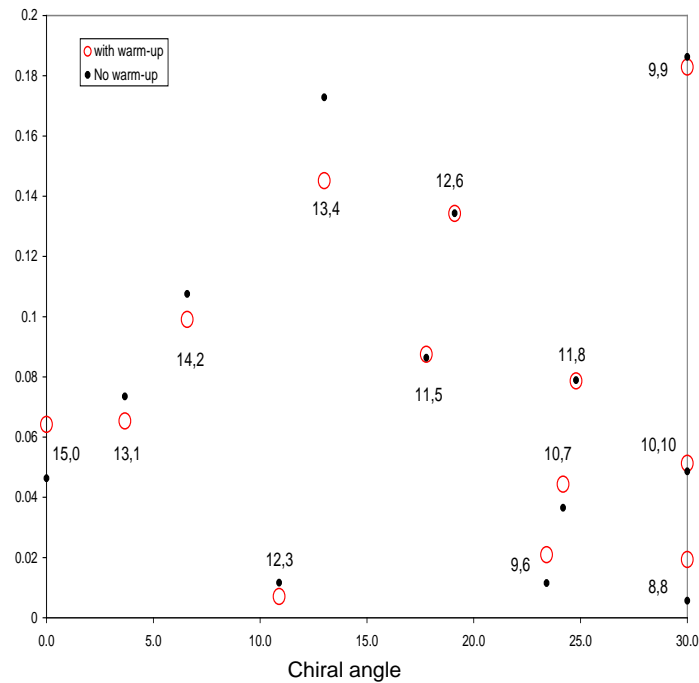
(12,6), (11,5), (13,4) and (14,2) decrease with warm-up
-all have chiral angles $<20^\circ$

(9,9) did not change

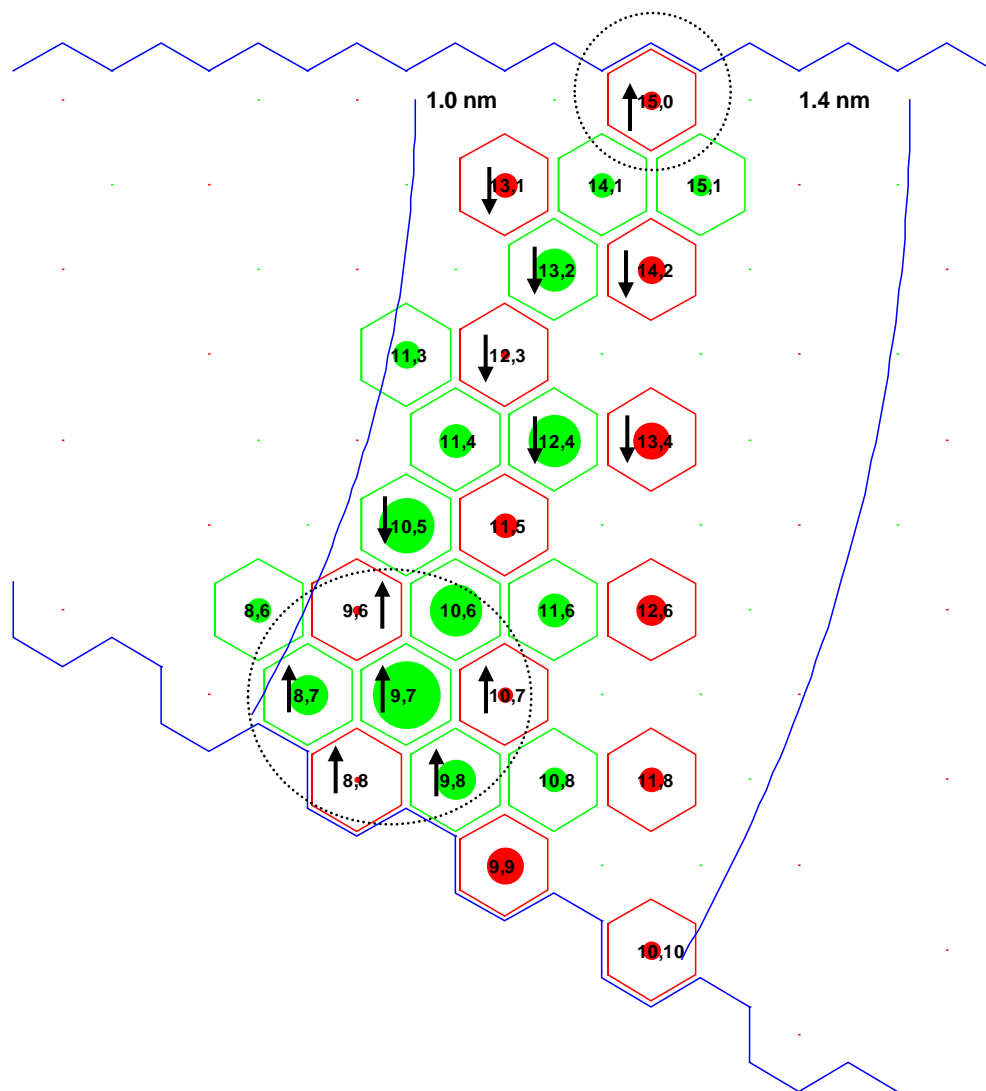
(15,0) and (13,1) increase with warm-up: smallest chiral angles

No clear diameter dependence

(12,0), (11,2) and (10,4) are not present on Raman spectra



Chiral map.



Conclusions

- Semiconducting nanotubes close to armchair structure increase
- Metallic nanotubes close to armchair structure increase
- 1 zig-zag metallic tube also increase
- The effect of “warm-up” on nanotube population is small, but definitely noticeable, considering that type population in PLV production is highly reproducible.
- Longer warm-up is needed. 5 ns pulse is only enough to raise temperature by ~180k for 100 μ s at most.
- Long-pulse laser? UV Hg flash lamp? Intensity ramp?
- Optimization with respect to the time delay. Nanotube nucleation timeline is still unknown. 500 μ s time delay used in this work is no more than an educated guess.

